

Product data sheet

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NXP Semiconductors



VHF variable capacitance diode

FEATURES

- Excellent linearity
- Ultra small plastic SMD package
- C28: 1 pF; ratio: 14.

APPLICATIONS

- Electronic tuning in satellite tuners
- Tuneable coupling
- Voltage controlled oscillators (VCO).

DESCRIPTION

The BB181 is a variable capacitance diode, fabricated in planar technology and encapsulated in the SOD523 (SC-79) ultra small plastic SMD package.

PINNING

PIN	DESCRIPTION
1	cathode
2	anode

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
V _R	continuous reverse voltage	_	30	V
I _F	continuous forward current	_	20	mA
T _{stg}	storage temperature	-55	+150	°C
Tj	operating junction temperature	-55	+150	°C

ELECTRICAL CHARACTERISTICS

 $T_i = 25 \ ^{\circ}C$ unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
I _R	reverse current	V _R = 30 V; see Fig.3	_	10	nA
		V _R = 30 V; T _j = 85 °C; see Fig.3	_	200	nA
r _s	diode series resistance	f = 470 MHz; note 1	_	3	Ω
C _d	diode capacitance	V_R = 0.5 V; f = 1 MHz; see Figs 2 and 4	8	17	pF
		$V_R = 28 V$; f = 1 MHz; see Figs 2 and 4	0.7	1.055	pF
$\frac{C_{d(0.5V)}}{C_{d(28V)}}$	capacitance ratio	f = 1 MHz	12	16	

Note

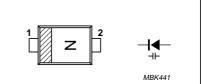
1. V_R is the value at which $C_d = 9 \text{ pF}$.



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BB181

Product specification



Orientation of marking code as shown.

Fig.1 Simplified outline

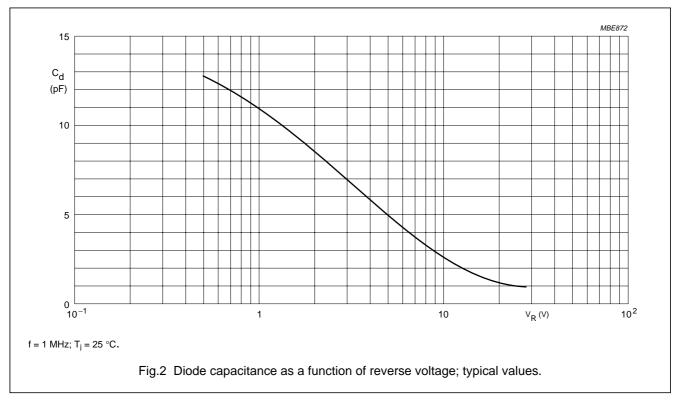
(SOD523; SC-79) and symbol.

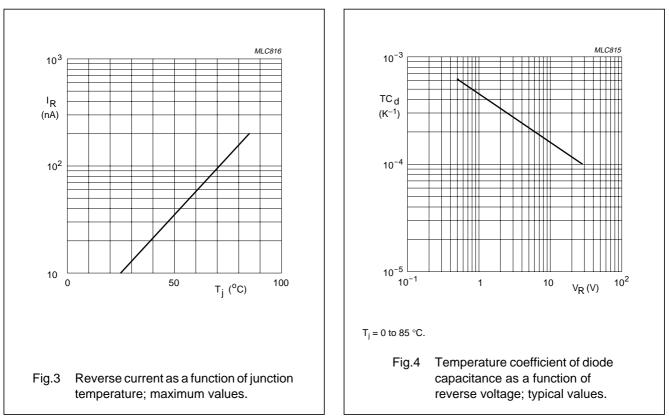
Cathode side indicated by a bar.

Marking code: N.

VHF variable capacitance diode

GRAPHICAL DATA



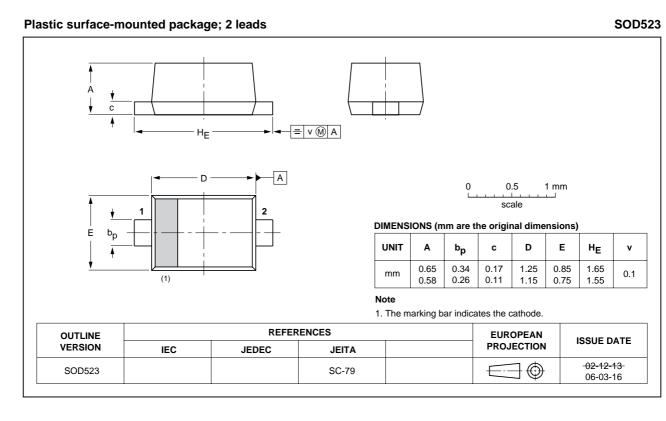


BB181

VHF variable capacitance diode

BB181

PACKAGE OUTLINE



Rev. 02 - 2 January 2008

Legal information

Data sheet status

Document status[1][2]	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

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Revision history

Revision history				
Document ID	Release date	Data sheet status	Change notice	Supersedes
BB181_N_2	20080102	Product data sheet	-	BB181_1
Modifications:	 Package ou 	tline drawing on page 4 cha	anged	
BB181_1 (9397 750 04886)	19981126	Product specification	-	-

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